

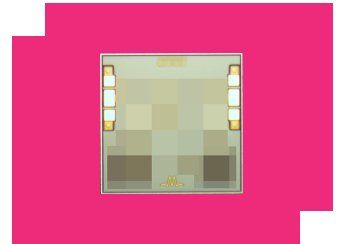
# MEQ3-7ACH

## Passive GaAs MMIC 7 GHz Equalizer

### DEVICE OVERVIEW

#### General Description

The MEQ3-7ACH passive MMIC equalizer die is an ideal solution for compensating for low pass filtering effects in RF/microwave and high speed digital systems. They provide positive slope from DC to 7GHz with DC attenuation options between 3 and 12dB. The unique design offers superior return loss to competitors. GaAs MMIC technology provides consistent unit-to-unit performance in a small, low cost form factor.



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#### Features

- DC attenuation options from 3 to 12dB
- Typical Insertion Loss 0.5dB at 7GHz
- VSWR < 1.3:1 Over Entire Band

#### Applications

- RF Transceivers
- High-Speed Data
- Telecom
- Cable Loss Compensation
- Amplifier Compensation

#### Functional Block

##### Diagram

N/A

#### Part Ordering Options

Part Number	Description	Package	Green Status	Product Lifecycle	Export Classification
MEQ3-7ACH	Passive GaAs MMIC 7 GHz Equalizer	CH	REACH RoHS	Released	EAR99

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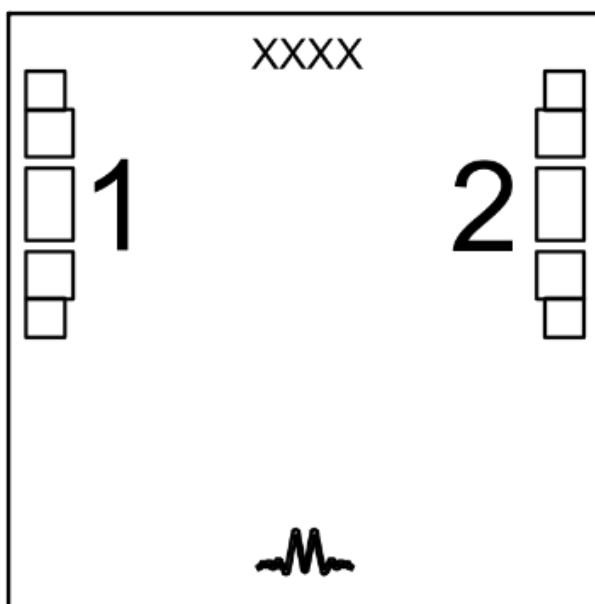
### Revision History

Revision Code	Revision Date	Comment
A	2024-01-05	Updated Production Test Criteria

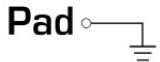
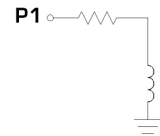

### Port Configuration and Functions

#### Port Diagram

A top-down view of the MEQ12-7A CH package outline drawing is shown below. The MEQ equalizers are symmetrical allowing Port 1 or Port 2 to be used as the input.



#### Port Functions

Port	Function	Description	Equivalent Circuit for Package
Pad	Ground	CH package ground path is provided through the substrate and ground bond pads.	
Pad 1	Input/Output	Port 1 is DC connected to ground through a resistor. DC block is required if voltage present.	
Pad 2	Output/Input	Port 2 is DC connected to ground through a resistor. DC block is required if voltage present.	

## Specifications

### Absolute Maximum Ratings

The Absolute Maximum Ratings indicate limits beyond which damage may occur to the device. If these limits are exceeded, the device may be inoperable or have a reduced lifetime.

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	100	°C
Maximum Storage Temperature	125	°C
Minimum Operating Temperature	-55	°C
Minimum Storage Temperature	-65	°C
Port 1 DC Current	40	mA
Port 2 DC Current	40	mA
Power Handling, at any Port	30	dBm

### Package Information

Parameter	Details	Rating
ESD	250 to < 500 Volts	HBM Class 1A
Dimensions	-	1.25 x 1.25 mm

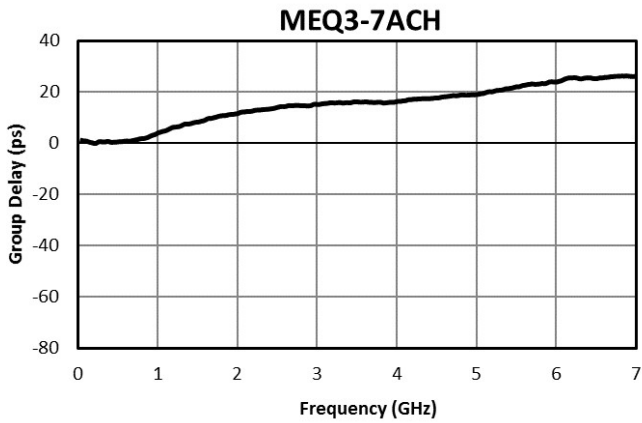
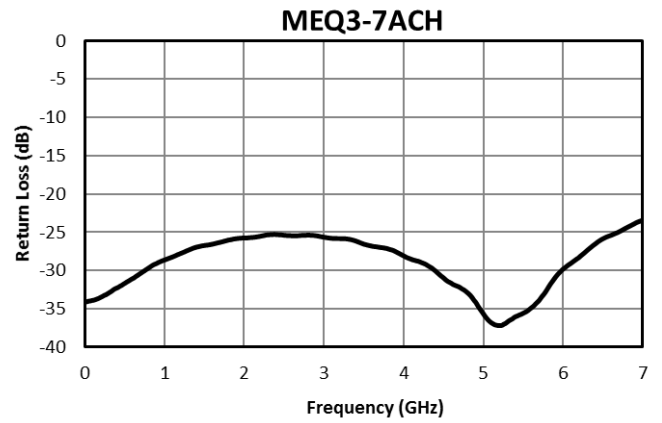
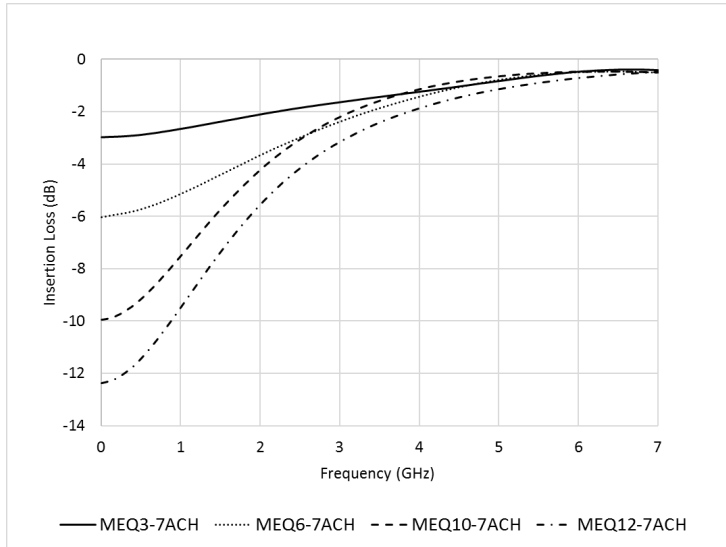
### Electrical Specifications

The electrical specifications apply at TA=+25°C in a 50Ω system. Min and Max limits are guaranteed at TA=+25°C. All bare die are 100% visually inspected and RF performance is guaranteed by sample testing.

Parameter	Test Conditions	Minimum Frequency (GHz)	Maximum Frequency (GHz)	Min	Typ	Max	Unit
Insertion Loss	Freq=0GHz	-	-	-	3	-	dB
Insertion Loss	Freq=7GHz	-	-	-	0.4	-	dB
Return Loss	Freq=7GHz	0	7	-	29	-	dB

Equalizer is symmetrical. Reverse measurement is equivalent to forward measurement.

### Typical Performance Plots



## Die Mounting Recommendations

### Mounting and Bonding Recommendations

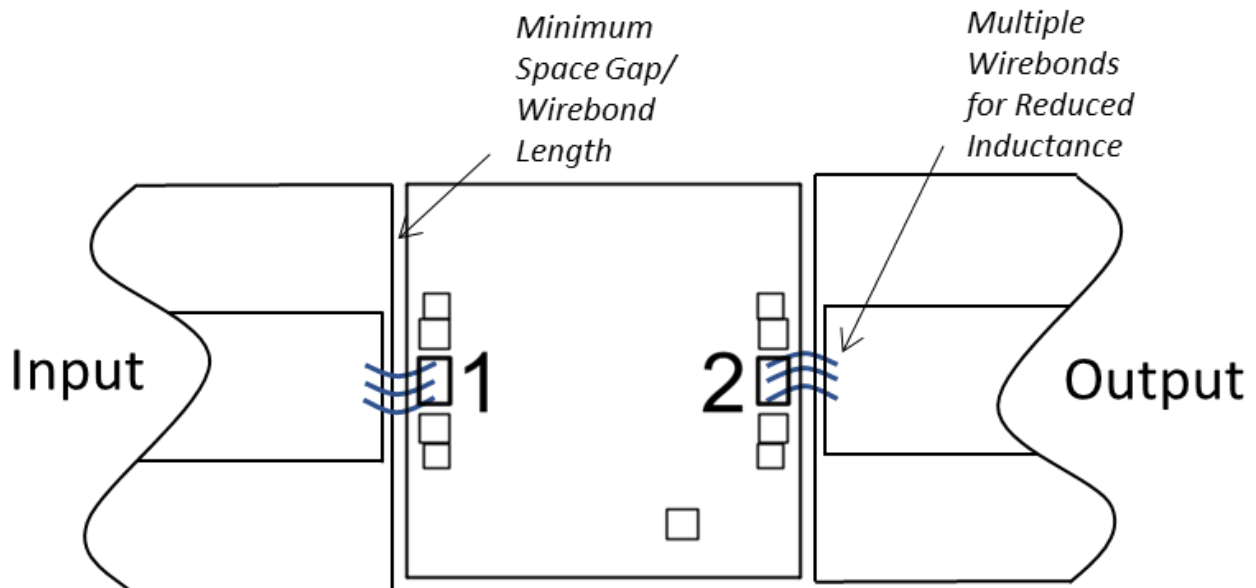
Marki MMICs should be attached directly to a ground plane with conductive epoxy. The ground plane electrical impedance should be as low as practically possible. This will prevent resonances and permit the best possible electrical performance. Datasheet performance is only guaranteed in an environment with a low electrical impedance ground.

**Mounting** - To epoxy the chip, apply a minimum amount of conductive epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip. Cure epoxy according to manufacturer instructions.

**Wire Bonding** - Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

**Circuit Considerations** - 50 Ω transmission lines should be used for all high frequency connections in and out of the chip. Wirebonds should be kept as short as possible, with multiple wirebonds recommended for higher frequency connections to reduce parasitic inductance. In circumstances where the chip more than .001" thinner than the substrate, a heat spreading spacer tab is optional to further reduce bondwire length and parasitic inductance.

### Bonding Diagram



## Handling Precautions

### General Handling

Chips should be handled with care using tweezers or a vacuum collet. Users should take precautions to protect chips from direct human contact that can deposit contaminants, like perspiration and skin oils on any of the chip's surfaces.

### Static Sensitivity

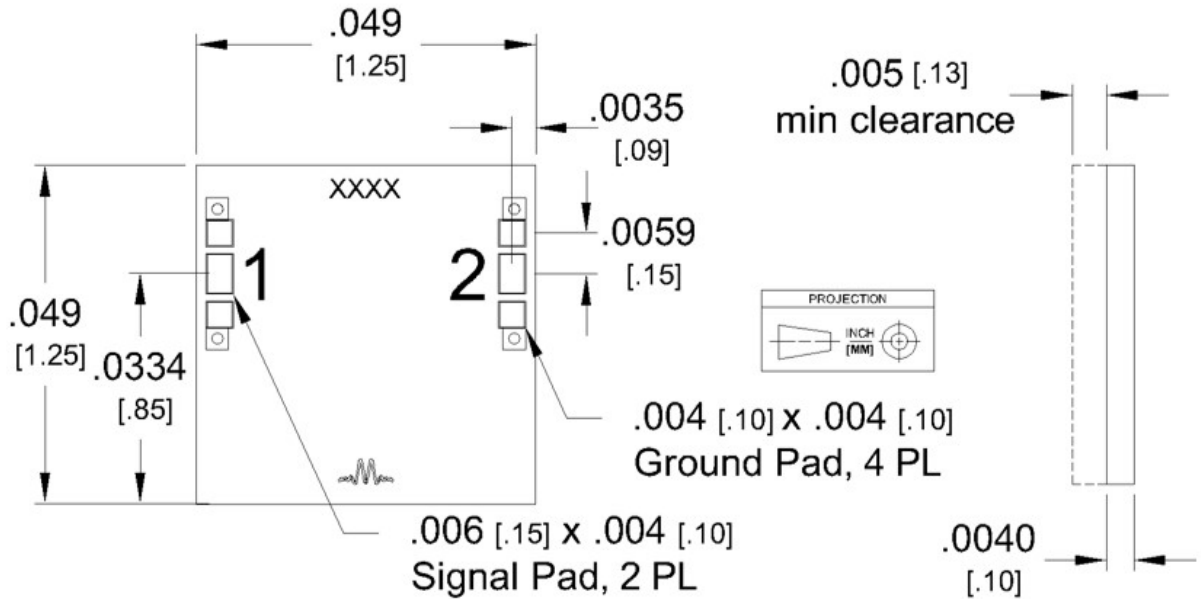
GaAs MMIC devices are sensitive to ESD and should be handled, assembled, tested, and transported only in static protected environments.

**Cleaning and Storage:** Do not attempt to clean the chip with a liquid cleaning system or expose the bare chips to liquid. Once the ESD sensitive bags the chips are stored in are opened, chips should be stored in a dry nitrogen atmosphere.



### Mechanical Data

### Outline Drawing



1. CH Substrate material is 0.004 in thick GaAs.
2. I/O trace finish is 4.2 microns Au. Ground plane finish is 5 microns Au.
3. XXXX denotes circuit number
4. Tolerance for X, Y dimensions is  $\pm 0.002$  in.  
Tolerance for Z dimension is  $\pm 0.0005$  in.  
Tolerance for pad location is  $\pm 0.0001$  in.

Part Number	Circuit Number
MEQ3-7ACH	6333
MEQ6-7ACH	6334
MEQ10-7ACH	6335
MEQ12-7ACH	6344

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